TEXAS INSTRUMENTS

TS5A22364

SCDS261H – MARCH 2008 – REVISED JUNE 2017

TS5A22364 0.65-Ω Dual SPDT Analog Switches With Negative Signaling Capability

1 Features

- Specified Break-Before-Make Switching
- Negative Signaling Capability: Maximum Swing from –2.75 V to 2.75 V (V_{CC} = 2.75 V)
- Internal Shunt Switch Prevents Audible Click-and-Pop When Switching Between Two Sources
- Low ON-State Resistance (0.65 Ω Typical)
- Low Charge Injection
- Excellent ON-State Resistance Matching
- 2.3-V to 5.5-V Power Supply (V_{CC})
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2500-V Human-Body Model (A114-B, Class II)
  - 1500-V Charged-Device Model (C101)
  - 200-V Machine Model (A115-A)

2 Applications

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio Routing
- Medical Imaging

3 Description

The TS5A22364 is a bidirectional, 2-channel, single-pole double-throw (SPDT) analog switch designed to operate from 2.3 V to 5.5 V. The device features negative signal capability that allows signals below ground to pass through the switch without distortion. Additionally, the TS5A22364 includes an internal shunt switch, which automatically discharges any capacitance at the NC or NO terminals when they are unconnected to COM. This reduces the audible click/pop noise when switching between two sources. The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications. The 3.00-mm x 3.00-mm DRC package is also available as a nonmagnetic package for medical imaging applications.

Device Information [(1)]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TS5A22364	VSON (10)	3.00 mm × 3.00 mm
	DSBGA (10)	1.90 mm × 1.40 mm
	VSSOP (10)	3.00 mm × 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.
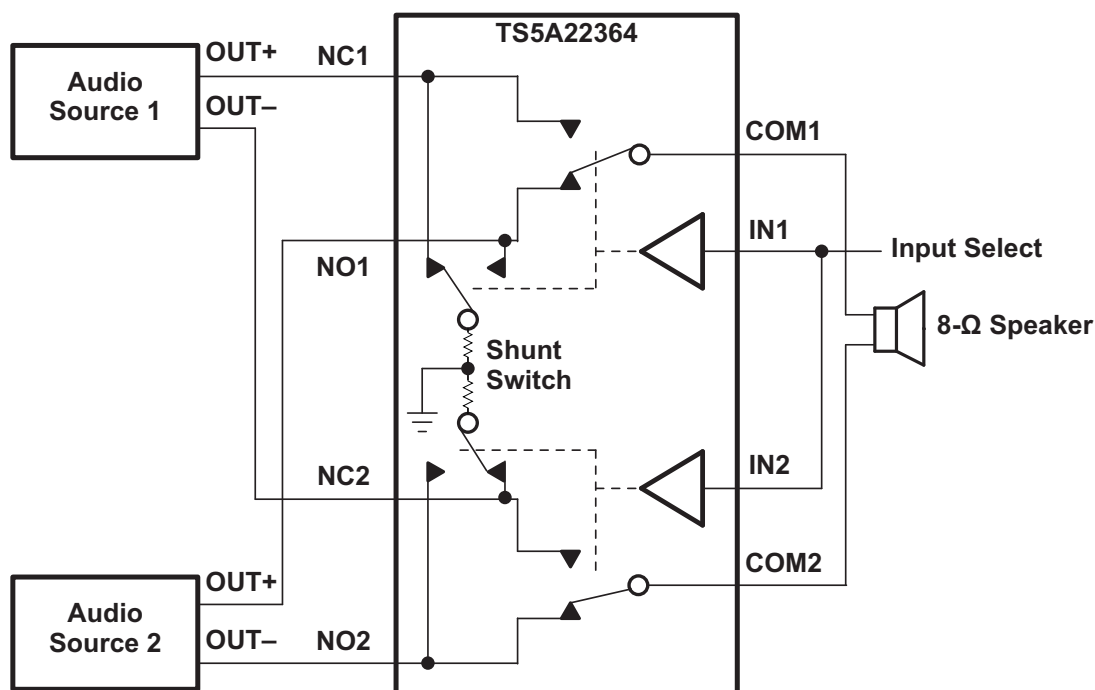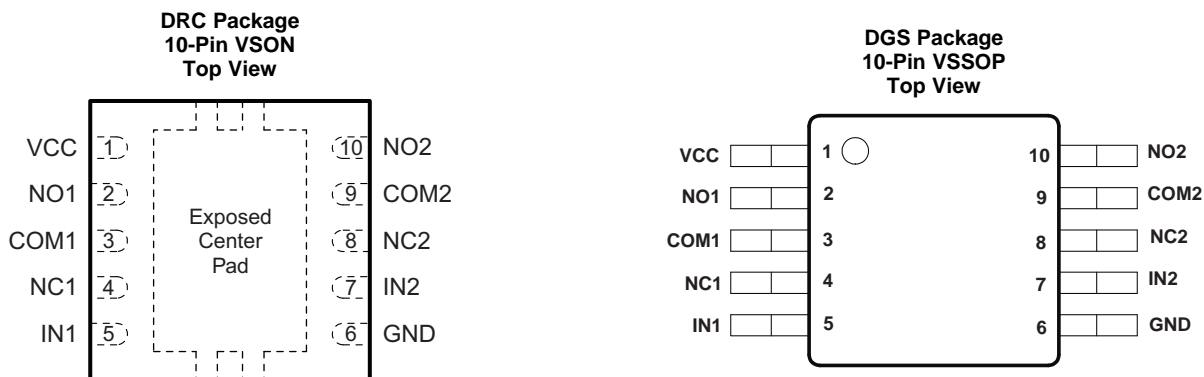
Typical Application Schematic
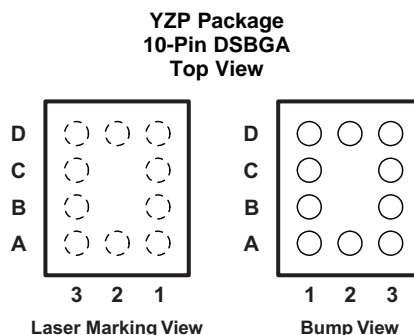
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (September 2015) to Revision H   **Page**

• Changed the V_{IN} MAX value From: V_{CC} To: 5.5 V in the *Recommended Operating Conditions* table 4

Changes from Revision F (June 2015) to Revision G   **Page**

• Changed C_L TEST CONDITION value for all THD PARAMETERs from 15 pf to 35 pf. 7

Changes from Revision E (May 2013) to Revision F   **Page**

• Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Recommended Operating Conditions* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section 1

• Split the TS5A22364 and TS5A22362 into separate datasheets and added verbiage to clarify the operation of the shunt resistor. 1

• Changed the max R_{on} spec from 1.04 Ω to 1.30 Ω at 2.7 V V_{CC} across full T_A. 5

Changes from Revision D (November 2011) to Revision E   **Page**

• Added *Absolute Maximum Ratings* textnote.. 4

Changes from Revision C (April 2010) to Revision D   **Page**

• Added Medical Imaging to *Applications*.. 1

5 Pin Configuration and Functions

**DRC Package
10-Pin VSON
Top View**

*The exposed center pad, if used, must be
connected as a secondary GND or left
electrically open.

**DGS Package
10-Pin VSSOP
Top View**

**YZP Package
10-Pin DSBGA
Top View**

Laser Marking View	Bump View

Pin Functions

PIN			TYPE	DESCRIPTION
NAME	DRC / DGS	YZP		
VCC	1	A2	—	Power Supply
NO1	2	A3	I/O	Normally Open (NO) signal path, Switch 1
COM1	3	B3	I/O	Common signal path, Switch 1
NC1	4	C3	I/O	Normally Closed (NC) signal path, Switch 1
IN1	5	D3	I	Digital control pin to connect COM1 to NO1, Switch 1
GND	6	D2	—	Ground
IN2	7	D1	I	Digital control pin to connect COM2 to NO2, Switch 2
NC2	8	C1	I/O	Normally Closed (NC) signal path, Switch 2
COM2	9	B1	I/O	Common signal path, Switch 2
NO2	10	A1	I/O	Normally Open (NO) signal Path, Switch 2

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) [1] [2]

			MIN	MAX	UNIT
V_{CC}	Supply voltage [3]		−0.5	6	V
V_{NC} V_{NO} V_{COM}	Analog voltage [3] [4] [5]		$V_{CC} − 6$	$V_{CC} + 0.5$	V
$I_{I/OK}$	Analog port diode current	V_{NC}, V_{NO}, V_{COM} < 0 or V_{NC}, V_{NO}, V_{COM} > V_{CC}	−50	50	mA
I_{NC} I_{NO} I_{COM}	ON-state switch current	V_{NC}, V_{NO}, V_{COM} = 0 to V_{CC}	−150	150	mA
	ON-state peak switch current [6]		−300	300	
I_{RSH}	OFF-state switch Shunt Resistor current		−20	20	
I_{NC} [3] [7] [8] I_{NO} [3] [7] [8] I_{COM} [3] [7] [8]	ON-state switch current	V_{NC}, V_{NO}, V_{COM} = 0 to V_{CC}	−350	350	mA
	ON-state peak switch current [6]		−500	500	
V_{IN}	Digital input voltage range		−0.5	6.5	V
I_{IK}	Digital input clamp current [3] [4]	V_I < 0	−50	50	mA
I_{CC} I_{GND}	Continuous current through V_{CC} or GND		−100	100	mA
T_{stg}	Storage temperature		−65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* . Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3) All voltages are with respect to ground, unless otherwise specified.
(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(5) This value is limited to 5.5 V maximum.
(6) Pulse at 1-ms duration < 10% duty cycle.
(7) V_{CC} = 3.0 V to 5.0 V, T_A = −40°C to 85°C.
(8) For YZP package only.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 [1]	±2500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 [2]	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	2.3	5.5	V
V_{NC} V_{NO} V_{COM}	Signal path voltage	$V_{CC} − 5.5$	V_{CC}	V
V_{IN}	Digital control	GND	5.5	V

6.4 Thermal Information

THERMAL METRIC [1]		TS5A22364			UNIT
		DGS (VSSOP)	DRC (VSON)	YZP (DSBGA)	
		10 PINS	10 PINS	10 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	163.3	44.3	90.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	56.4	70.1	0.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	83.1	19.3	8.3	°C/W
ψ_{JT}	Junction-to-top characterization parameter	6.8	2.0	3.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	81.8	19.4	8.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	6.2	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics for 2.5-V Supply

V_{CC} = 2.3 V to 2.7 V, T_A = –40°C to 85°C (unless otherwise noted) [1]

PARAMETER		TEST CONDITIONS		T_A	V_{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH									
V_{COM}, V_{NO}, V_{NC}	Analog signal range					V_{CC} – 5.5		V_{CC}	V
R_{on}	ON-state resistance	V_{NC} or V_{NO} = V_{CC}, 1.5 V, V_{CC} – 5.5 V I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	2.3 V		0.65	0.94	Ω
				Full				1.3	
				25°C	2.7 V		0.65	0.94	Ω
				Full				1.3	
ΔR_{on}	ON-state resistance match between channels	V_{NC} or V_{NO} = 1.5 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	2.7 V		0.023	0.11	Ω
				Full				0.15	
$R_{on(flat)}$	ON-state resistance flatness	V_{NC} or V_{NO} = V_{CC}, 1.5 V, V_{CC} – 5.5 V I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	2.7 V		0.18	0.46	Ω
				Full				0.5	
R_{SH}	Shunt switch resistance	I_{NO} or I_{NC} = 10 mA		Full	2.7 V		25	50	Ω
$I_{COM(ON)}$	COM ON leakage current	V_{NC} and V_{NO} = Floating, V_{COM} = V_{CC}, V_{CC} – 5.5 V,	See Figure 15	25°C	2.7 V	–50		50	nA
				Full		–375		375	
DIGITAL CONTROL INPUTS (IN) [2]									
V_{IH}	Input logic high			Full		1.4		5.5	V
V_{IL}	Input logic low							0.4	
I_{IH}, I_{IL}	Input leakage current	V_{IN} = V_{CC} or 0		25°C	2.7 V	–250		250	nA
				Full		–250		250	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Floating digital inputs will cause excessive current consumption. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

Electrical Characteristics for 2.5-V Supply (continued)

V_{CC} = 2.3 V to 2.7 V, T_A = –40°C to 85°C (unless otherwise noted) [1]

PARAMETER		TEST CONDITIONS		T_A	V_{CC}	MIN	TYP	MAX	UNIT
DYNAMIC									
t_{ON}	Turnon time	$V_{COM} = V_{CC}$, R_L = 300 Ω,	C_L = 35 pF, see Figure 17	25°C	2.5 V		44	80	ns
				Full	2.3 V to 2.7 V			120	
t_{OFF}	Turnoff time	$V_{COM} = V_{CC}$, R_L = 300 Ω,	C_L = 35 pF, see Figure 17	25°C	2.5 V		22	70	ns
				Full	2.3 V to 2.7 V			70	
t_{BBM}	Break-before-make time	See Figure 18		25°C	2.5 V	1	7		ns
Q_C	Charge injection	V_{GEN} = 0, R_{GEN} = 0	C_L = 1 nF, see Figure 22	25°C	2.5 V		215		pC
$C_{COM(ON)}$	NC, NO, COM ON capacitance	$V_{COM} = V_{CC}$ or GND, Switch ON, f = 10 MHz	See Figure 16	25°C	2.5 V		370		pF
C_I	Digital input capacitance	$V_{IN} = V_{CC}$ or GND	See Figure 16	25°C	2.5 V		2.6		pF
BW	Bandwidth	R_L = 50 Ω, –3 dB		25°C	2.5 V		17		MHz
O_{ISO}	OFF isolation	R_L = 50 Ω	f = 100 kHz, see Figure 20	25°C	2.5 V		–66		dB
X_{TALK}	Crosstalk	R_L = 50 Ω	f = 100 kHz, see Figure 21	25°C	2.5 V		–75		dB
THD	Total harmonic distortion	R_L = 600 Ω, C_L = 35 pF,	f = 20 Hz to 20 kHz, see Figure 23	25°C	2.5 V		0.01%		
SUPPLY									
I_{CC}	Positive supply current	V_{COM} and $V_{IN} = V_{CC}$ or GND, V_{NC} and V_{NO} = Floating		25°C	2.7 V		0.2	1.1	µA
				Full				1.3	
		$V_{COM} = V_{CC}$ – 5.5, $V_{IN} = V_{CC}$ or GND, V_{NC} and V_{NO} = Floating		Full	2.7 V			3.3	µA

6.6 Electrical Characteristics for 3.3-V Supply

V_{CC} = 3 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted) [1]

PARAMETER		TEST CONDITIONS		T_A	V_{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH									
V_{COM}, V_{NO}, V_{NC}	Analog signal range					V_{CC} – 5.5		V_{CC}	V
R_{on}	ON-state resistance	V_{NC} or $V_{NO} ≤ V_{CC}$, 1.5 V, V_{CC} – 5.5 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	3 V		0.61	0.87	Ω
				Full				0.97	
ΔR_{on}	ON-state resistance match between channels	V_{NC} or V_{NO} = 1.5 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	3 V		0.024	0.13	Ω
				Full				0.13	
$R_{on(flat)}$	ON-state resistance flatness	V_{NC} or $V_{NO} ≤ V_{CC}$, 1.5 V, V_{CC} – 5.5 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	3 V		0.12	0.46	Ω
				Full				0.5	
R_{SH}	Shunt switch resistance	I_{NO} or I_{NC} = 10 mA		Full	3 V		25	37	Ω
$I_{COM(ON)}$	COM ON leakage current	V_{NC} and V_{NO} = Open, $V_{COM} = V_{CC}$, V_{CC} – 5.5 V,	COM to NO or NC, see Figure 15	25°C	3.6 V	–50		50	nA
				Full		–375		375	
DIGITAL CONTROL INPUTS (IN) [2]									
V_{IH}	Input logic high			Full		1.4		5.5	V
V_{IL}	Input logic low							0.6	
I_{IH}, I_{IL}	Input leakage current	$V_{IN} = V_{CC}$ or 0		25°C	3.6 V	–250		250	nA
				Full		–250		250	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Floating digital inputs will cause excessive current consumption. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

Electrical Characteristics for 3.3-V Supply (continued)

V_{CC} = 3 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted) [1]

PARAMETER		TEST CONDITIONS		T_A	V_{CC}	MIN	TYP	MAX	UNIT
DYNAMIC									
t_{ON}	Turnon time	$V_{COM} = V_{CC}$, R_L = 300 Ω,	C_L = 35 pF, see Figure 17	25°C	3.3 V		34	80	ns
				Full	3 V to 3.6 V			120	
t_{OFF}	Turnoff time	$V_{COM} = V_{CC}$, R_L = 300 Ω,	C_L = 35 pF, see Figure 17	25°C	3.3 V		19	70	ns
				Full	3 V to 3.6 V			70	
t_{BBM}	Break-before-make time	See Figure 18		25°C	3.3 V	1	7		ns
Q_C	Charge injection	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, see Figure 22	25°C	3.3 V		300		pC
$C_{COM(ON)}$	NC, NO, COM ON capacitance	$V_{COM} = V_{CC}$ or GND, f = 10 MHz	See Figure 16	25°C	3.3 V		370		pF
C_I	Digital input capacitance	$V_{IN} = V_{CC}$ or GND	See Figure 16	25°C	3.3 V		2.6		pF
BW	Bandwidth	R_L = 50 Ω, –3 dB	Switch ON,	25°C	3.3 V		17.5		MHz
O_{ISO}	OFF isolation	R_L = 50 Ω,	f = 100 kHz, see Figure 20	25°C	3.3 V		–68		dB
X_{TALK}	Crosstalk	R_L = 50 Ω,	f = 100 kHz, see Figure 21	25°C	3.3 V		–76		dB
THD	Total harmonic distortion	R_L = 600 Ω, C_L = 35 pF,	f = 20 Hz to 20 kHz, see Figure 23	25°C	3.3 V		0.008%		
SUPPLY									
I_{CC}	Positive supply current	V_{COM} and $V_{IN} = V_{CC}$ or GND, V_{NC} and V_{NO} = Floating		25°C	3.6 V		0.1	1.2	µA
				Full				1.3	
		$V_{COM} = V_{CC}$ – 5.5 V, $V_{IN} = V_{CC}$ or GND, V_{NC} and V_{NO} = Floating		Full	3.6 V			3.4	µA

6.7 Electrical Characteristics for 5-V Supply

V_{CC} = 4.5 V to 5.5 V, T_A = –40°C to 85°C (unless otherwise noted) [1]

PARAMETER		TEST CONDITIONS		T_A	V_{CC}	MIN	TYP	MAX	UNIT
ANALOG SWITCH									
V_{COM}, V_{NO}, V_{NC}	Analog signal range					$V_{CC} - 5.5$		V_{CC}	V
R_{on}	ON-state resistance	V_{NC} or V_{NO} = V_{CC}, 1.6 V, V_{CC} = –5.5 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	4.5 V		0.52	0.74	Ω
				Full				0.83	
ΔR_{on}	ON-state resistance match between channels	V_{NC} or V_{NO} = 1.6 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	4.5 V		0.04	0.23	Ω
				Full				0.30	
$R_{on(flat)}$	ON-state resistance flatness	V_{NC} or V_{NO} = V_{CC}, 1.6 V, V_{CC} = –5.5 V, I_{COM} = –100 mA,	COM to NO or NC, see Figure 13	25°C	4.5 V		0.076	0.46	Ω
				Full				0.5	
R_{SH}	Shunt switch resistance	I_{NO} or I_{NC} = 10 mA		Full	4.5 V		16	36	Ω
$I_{COM(ON)}$	COM ON leakage current	V_{NC} and V_{NO} = Open, V_{COM} = V_{CC}, V_{CC} – 5.5 V,	See Figure 15	25°C	5.5 V	–50		50	nA
				Full		–375		375	
DIGITAL CONTROL INPUTS (IN) [2]									
V_{IH}	Input logic high			Full		2.4		5.5	V
V_{IL}	Input logic low							0.8	
I_{IH}, I_{IL}	Input leakage current	V_{IN} = V_{CC} or 0		25°C	5.5 V	–250		250	nA
				Full		–250		250	
DYNAMIC									
t_{ON}	Turnon time	V_{COM} = V_{CC}, R_L = 300 Ω,	C_L = 35 pF, see Figure 17	25°C	5 V		27	80	ns
				Full	4.5 V to 5.5 V			80	
t_{OFF}	Turnoff time	V_{COM} = V_{CC}, R_L = 300 Ω,	C_L = 35 pF, see Figure 17	25°C	5 V		13	70	ns
				Full	4.5 V to 5.5 V			70	
t_{BBM}	Break-before-make time	V_{NC} = V_{NO} = V_{CC}/2 R_L = 300 Ω,	C_L = 35 pF,	25°C	5 V	1	3.5		ns
Q_C	Charge injection	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, see Figure 22	25°C	5 V		500		pC
$C_{COM(ON)}$	NC, NO, COM ON capacitance	V_{COM} = V_{CC} or GND,	See Figure 16	25°C	5 V		370		pF
C_I	Digital input capacitance	V_{IN} = V_{CC} or GND	See Figure 16	25°C	5 V		2.6		pF
BW	Bandwidth	R_L = 50 Ω,		25°C	5 V		18.3		MHz
O_{ISO}	OFF isolation	R_L = 50 Ω,	f = 100 kHz, see Figure 20	25°C	5 V		–70		dB
X_{TALK}	Crosstalk	R_L = 50 Ω,	f = 100 kHz, see Figure 21	25°C	5 V		–78		dB
THD	Total harmonic distortion	R_L = 600 Ω, C_L = 35 pF,	f = 20 Hz to 20 kHz, see Figure 23	25°C	5 V		0.009%		
SUPPLY									
I_{CC}	Positive supply current	V_{COM} and V_{IN} = V_{CC} or GND, V_{NC} and V_{NO} = Floating		25°C	5.5 V		0.2	1.3	µA
				Full				3.5	
		V_{COM} = V_{CC} – 5.5, V_{IN} = V_{CC} or GND, V_{NC} and V_{NO} = Floating		Full				5	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Floating digital inputs will cause excessive current consumption. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.
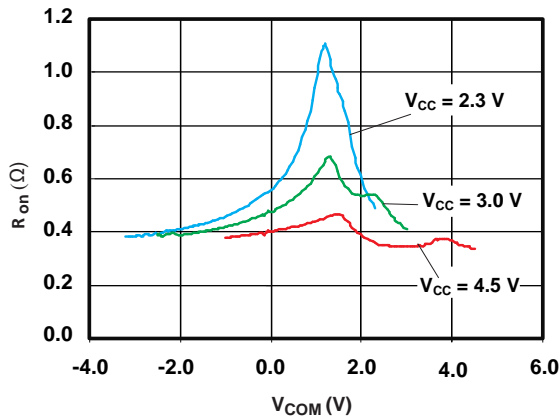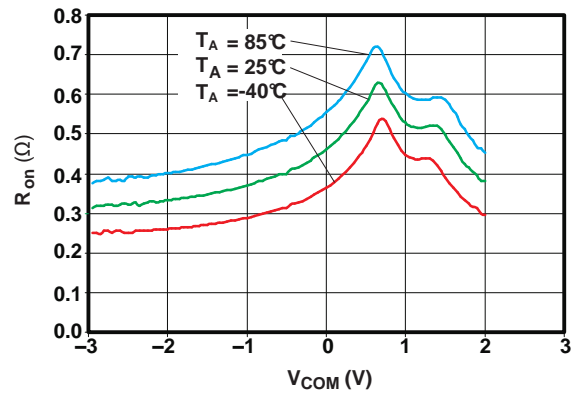
6.8 Typical Characteristics

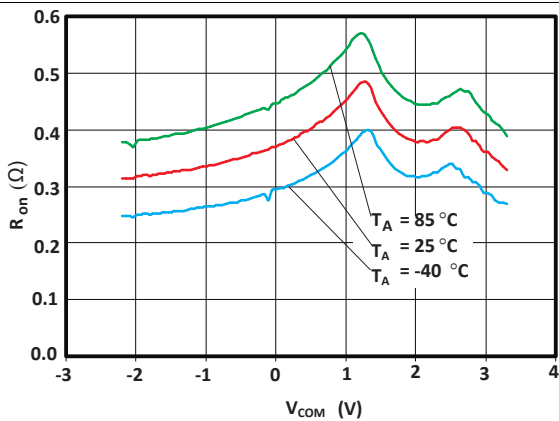Figure 1. R_on vs V_COM

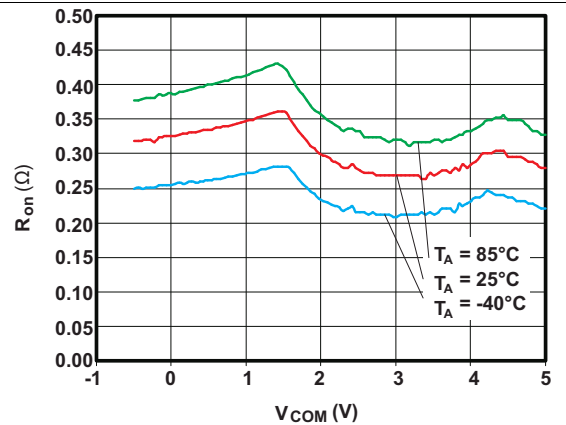Figure 2. R_on vs V_COM (V_CC = 2.7 V)

Figure 3. R_on vs V_COM (V_CC = 3.3 V)

Figure 4. R_on vs V_COM (V_CC = 5 V)
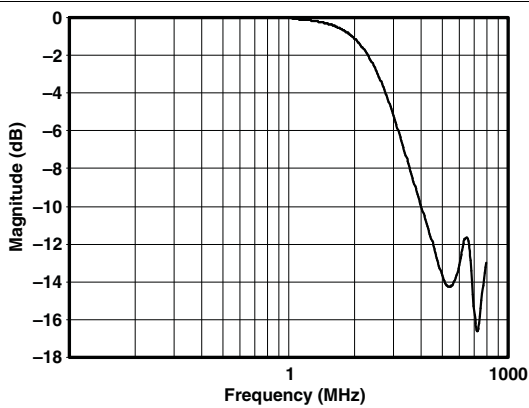
Figure 5. Insertion Loss
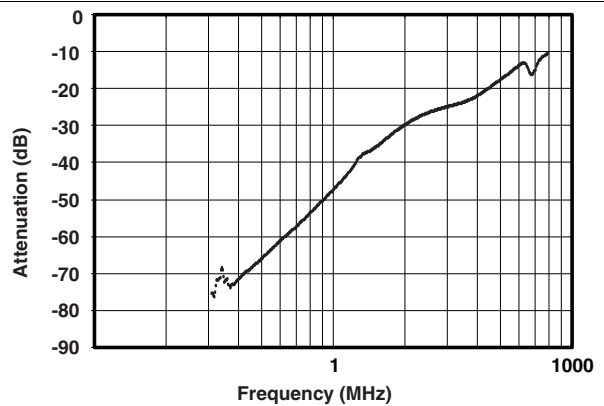
Figure 6. Off Isolation vs Frequency

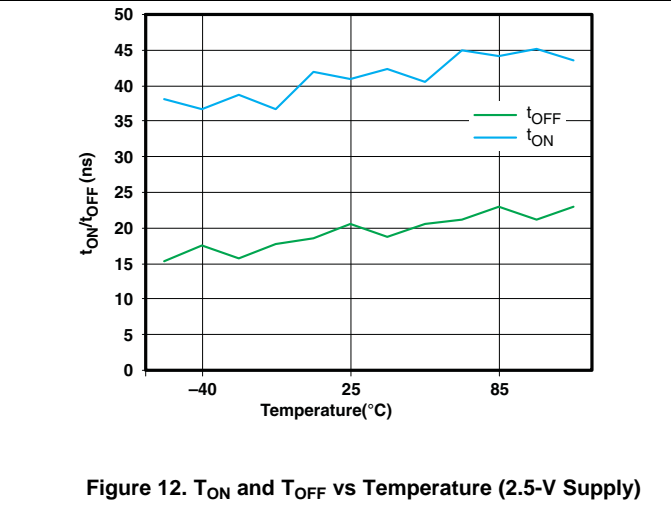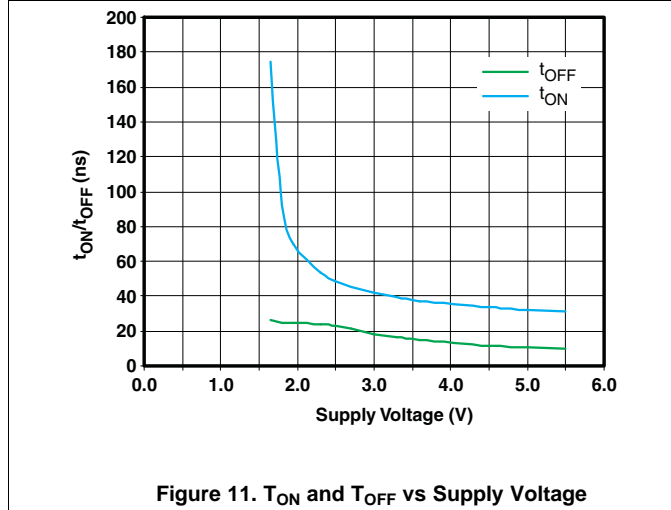Product Folder Links: TS5A22364

Typical Characteristics (continued)

Figure 7. Charge Injection (Q_C) vs V_{COM}

Figure 8. Crosstalk (V_{CC} = 3.3 V)

Figure 9. Total Harmonic Distortion vs Frequency

Figure 10. Power-Supply Current vs V_{CC}

Figure 11. T_{ON} and T_{OFF} vs Supply Voltage

Figure 12. T_{ON} and T_{OFF} vs Temperature (2.5-V Supply)

Product Folder Links: *TS5A22364*
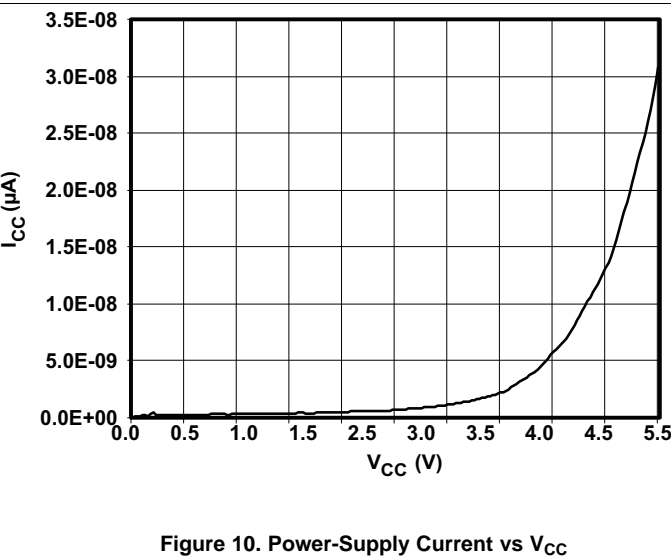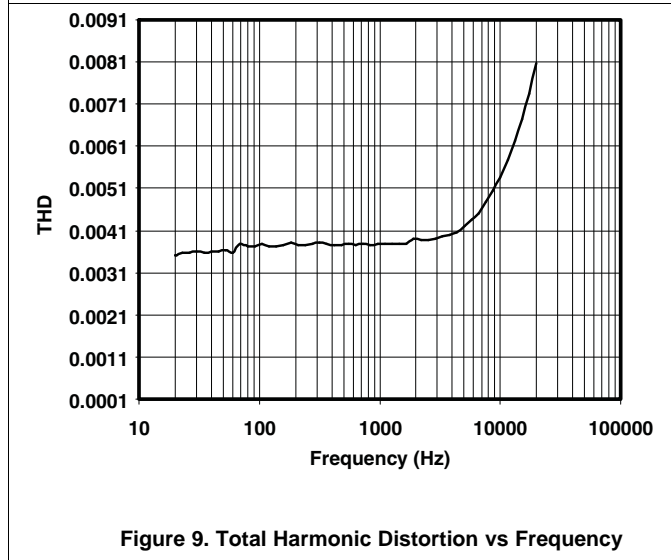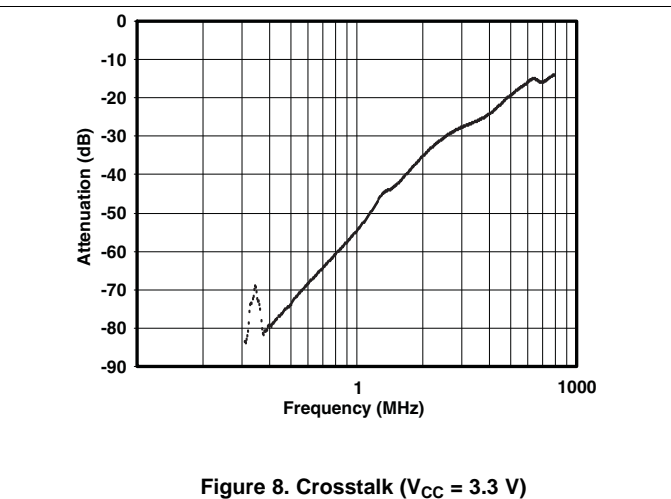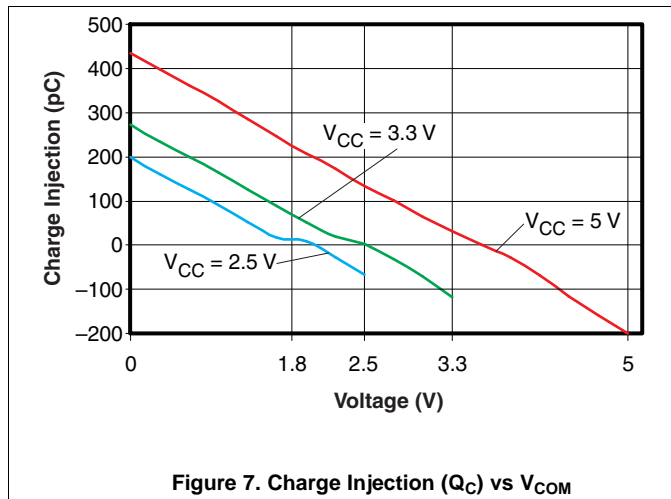
7 Parameter Measurement Information
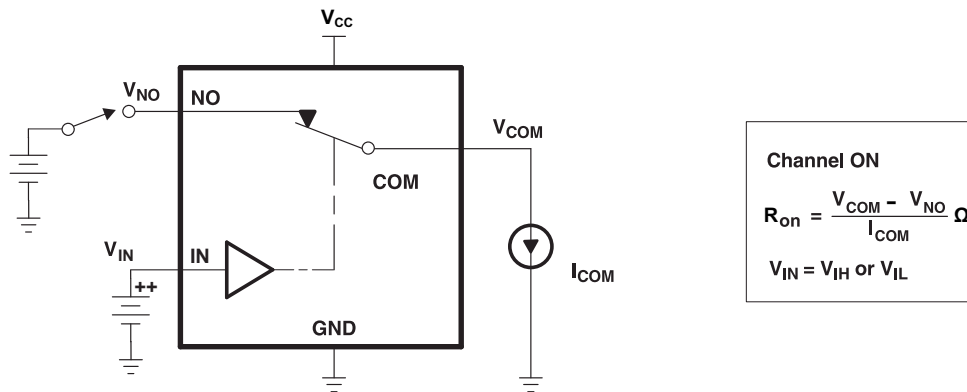
Figure 13. ON-State Resistance (R_on)

Channel ON

$$R_{on} = \frac{V_{COM} - V_{NO}}{I_{COM}} \; \Omega$$

$$V_{IN} = V_{IH} \text{ or } V_{IL}$$
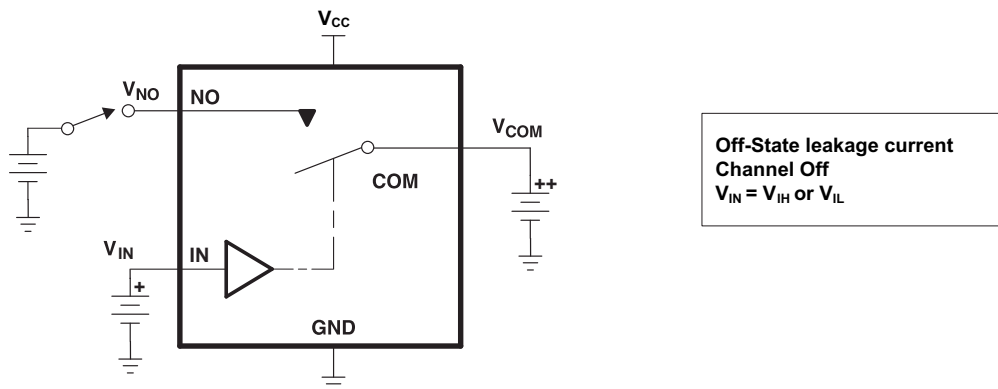
Figure 14. OFF-State Leakage Current (I_COM(OFF), I_NO(OFF))

Off-State leakage current
Channel Off
$V_{IN} = V_{IH}$ or V_{IL}
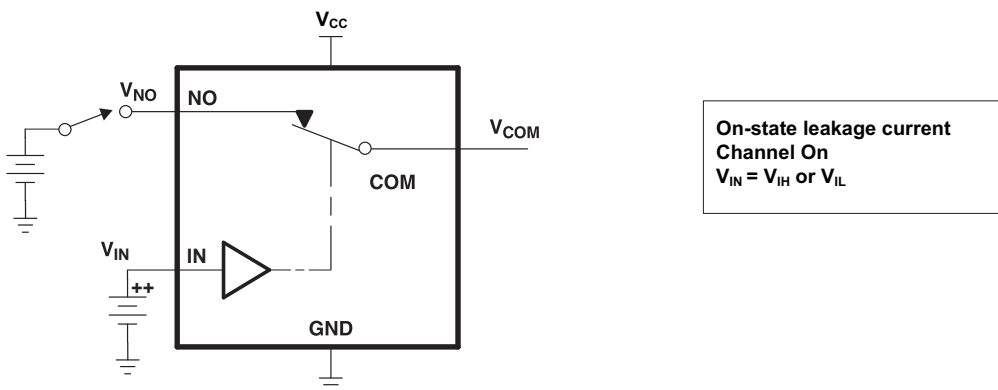
Figure 15. ON-State Leakage Current
(I_COM(ON), I_NO(ON))

On-state leakage current
Channel On
$V_{IN} = V_{IH}$ or V_{IL}

Parameter Measurement Information (continued)

$V_{BIAS} = V_{CC}$ or GND and
$V_{IN} = V_{IH}$ or V_{IL}
Capacitance is measured at NO, COM, and IN inputs during ON and OFF conditions.
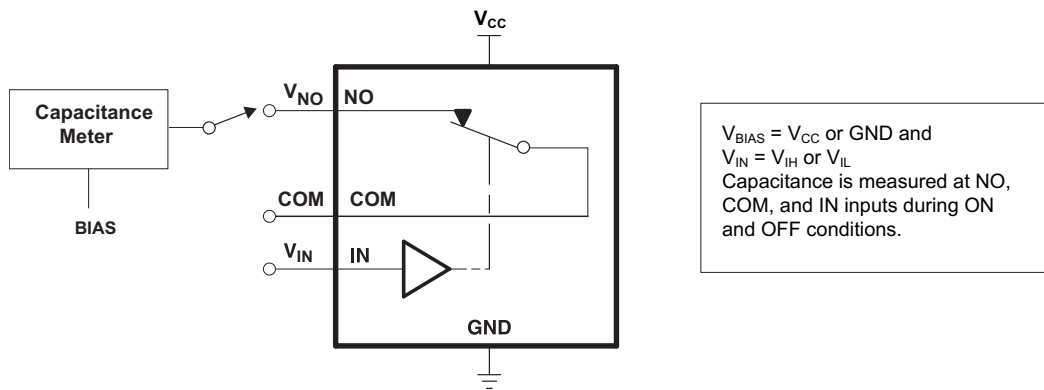
Figure 16. Capacitance
(C_I, $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NO(OFF)}$, $C_{NO(ON)}$)
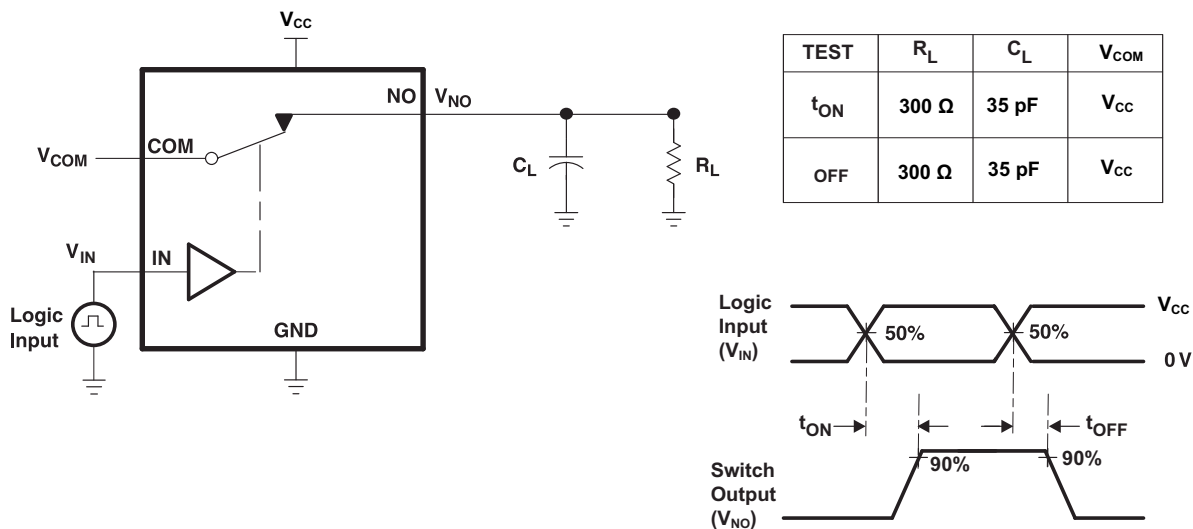
TEST	R_L	C_L	V_{COM}
t_{ON}	300 Ω	35 pF	V_{CC}
OFF	300 Ω	35 pF	V_{CC}

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.

B. C_L includes probe and jig capacitance.

Figure 17. Turnon (t_{ON}) and Turnoff Time (t_{OFF})

Parameter Measurement Information (continued)
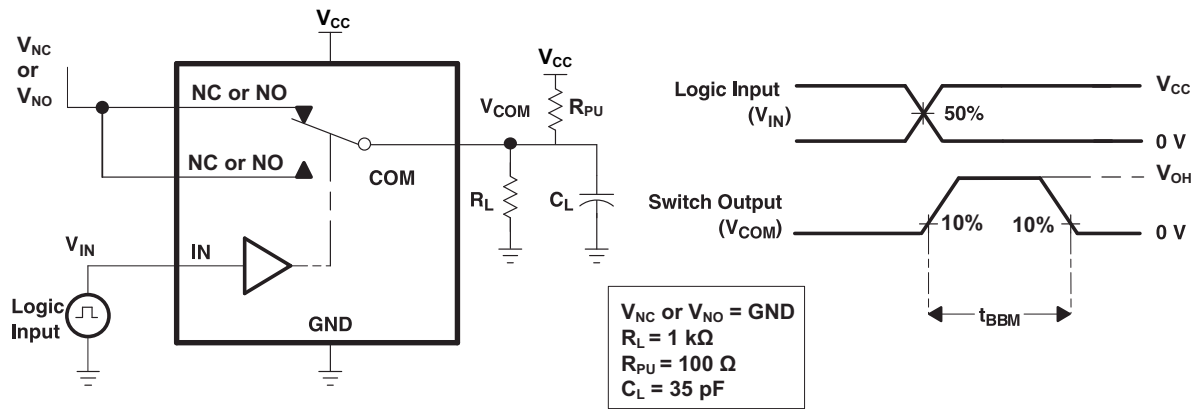
A. C_L includes probe and jig capacitance.

B.   All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.
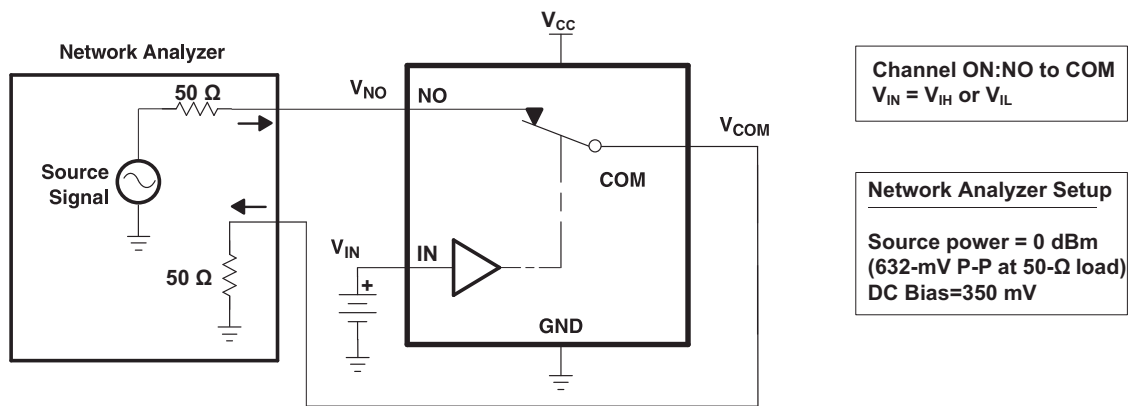
Figure 18. Break-Before-Make Time (t_{BBM})

Figure 19. Bandwidth (BW)
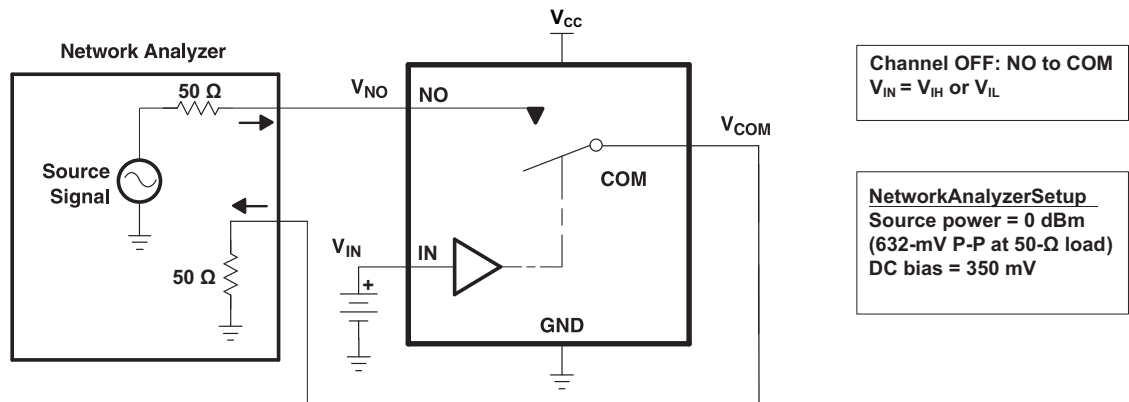
Figure 20. OFF Isolation (O_{ISO})

Submit Documentation Feedback   13

Product Folder Links: *TS5A22364*

Parameter Measurement Information (continued)

Figure 21. Crosstalk (X$_{TALK}$)

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z$_O$ = 50 Ω, t$_r$ < 5 ns, t$_f$ < 5 ns.

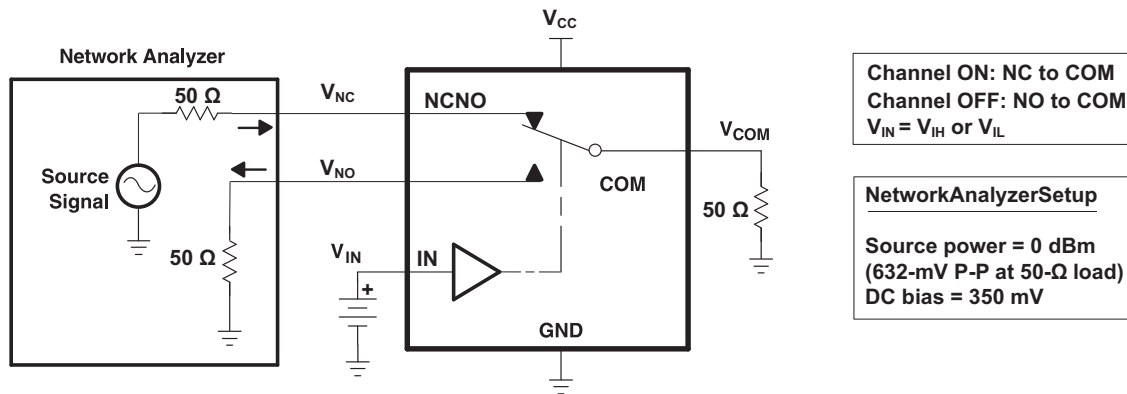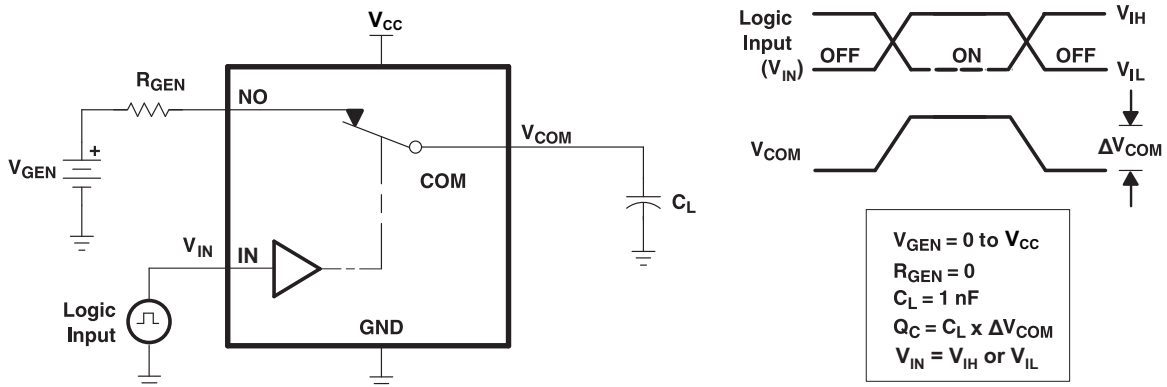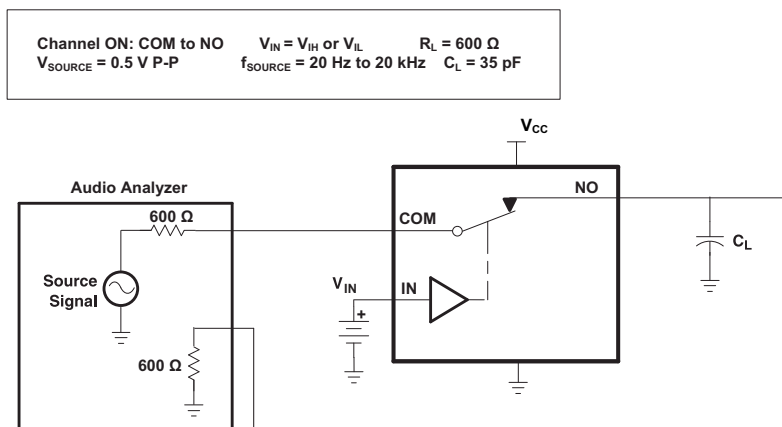B. C$_L$ includes probe and jig capacitance.

Figure 22. Charge Injection (Q$_C$)

C$_L$ includes probe and jig capacitance.

Figure 23. Total Harmonic Distortion (THD)

Product Folder Links: *TS5A22364*

8 Detailed Description

8.1 Overview

The TS5A22364 is a bidirectional 2-channel, single-pole, double-throw (SPDT) analog switch designed to operate from 2.3-V to 5.5-V power supply. The device features negative signal swing capability that allows signals below ground to pass through the switch without distortion. Additionally, the TS5A22364 includes an internal shunt switch, which automatically discharges any capacitance at the NC or NO terminals when they are not connected to COM. Discharging the capacitance reduces the audible click and pop noise when switching between two sources. The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications.

8.2 Functional Block Diagram
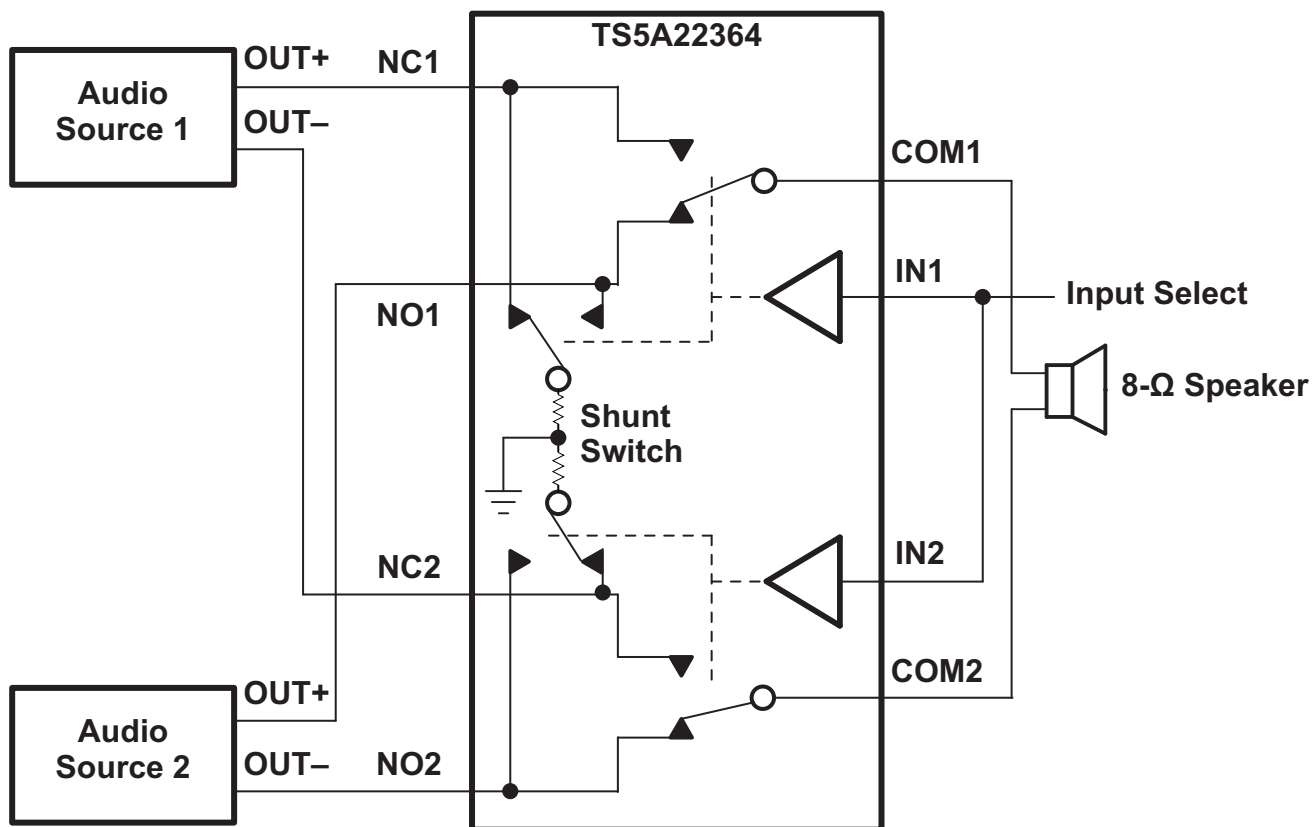
8.3 Feature Description

8.3.1 Click and Pop Reduction

The shunt resistors in the TS5A22364 automatically discharge any capacitance at the NC or NO terminals when they are not connected to COM. This reduces the audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not connected, any residual DC voltage is removed, thereby reducing the clicks and pops.

8.3.2 Negative Signal Swing Capability

The TS5A22364 2-channel SPDT switch features negative signal capability that allows signals below ground to pass through without distortion. These analog switches operate from a single 2.3-V to 5.5-V supply. The input and output signal swing of the device is dependant of the supply voltage V_{CC}. The device passes signals as high as V_{CC} and as low as V_{CC} – 5.5 V, including signals below ground with minimal distortion. The OFF state signal path (either NC or NO) during the operation of TS5A22364 cannot handle negative DC voltage

Table 1 shows the input/output signal swing the user can get with different supply voltages.

Table 1. Input/Output Signal Swing

SUPPLY VOLTAGE, V_{CC}	MINIMUM V_{NC}, V_{NO}, V_{COM} = V_{CC} - 5.5 V	MAXIMUM V_{NC}, V_{NO}, V_{COM} = V_{CC}
	ON-STATE SIGNAL PATH	
5.5 V	0 V	5.5 V
4.5 V	−1.0 V	4.5 V
3.6 V	−1.9 V	3.6 V
3.0 V	−2.5 V	3.0 V
2.7 V	−2.8 V	2.7 V
2.3 V	-3.2 V	2.3 V

8.4 Device Functional Modes

The function table for TS5A22364 is shown in Table 2.

Table 2. Function Table

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON

9   Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1   Application Information

The shunt resistors on the TS5A22364 automatically discharge any capacitance at the NC or NO terminals when they are not connected to COM. This reduces audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not connected, any residual DC voltage is removed, thereby reducing the clicks and pops.

9.2   Typical Application

The shunt resistors on the TS5A22364 are designed to automatically discharge any residual charge at the NC or NO terminals when they are not connected to COM. This reduces audible click-and-pop sounds that occur when switching between audio sources. Audible clicks and pops are caused when a step DC voltage is switched into the speaker. By automatically discharging the side that is not used for the signal path, any residual charge voltage is discharged to ground, thereby reducing the clicks and pops. The amount of power that the shunt switch can discharge from the inactive signal path is limited by the shunt resistors (Rsh) power dissipation. TI recommends that during operation, the current through the shunt path should be limited to ±10 mA.
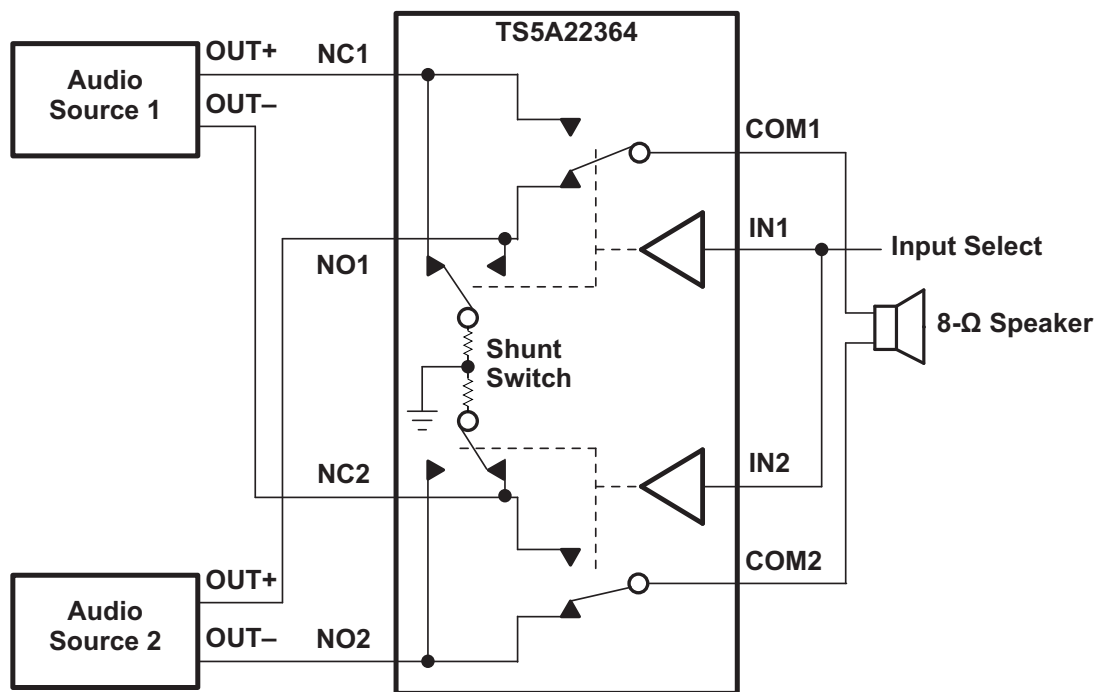
Figure 24. Shunt Switch (TS5A22364)

Typical Application (continued)

9.2.1 Design Requirements

Tie the digitally controlled inputs select pins IN1 and IN2 to V_{CC} or GND to avoid unwanted switch states and high current consumption that could result if the logic control pins are left floating.

9.2.2 Detailed Design Procedure

Select the appropriate supply voltage to cover the entire voltage swing of the signal passing through the switch because the TS5A22364 operates from a single 2.3-V to 5.5-V supply and the input and output signal swing of the device is dependant of the supply voltage, V_{CC}. The device will pass signals as high as V_{CC} and as low as V_{CC} – 5.5 V. Use Table 1 as a guide for selecting supply voltage based on the signal passing through the ON-state switch path.

Ensure that the device is powered up with a valid supply voltage on VCC before a voltage can be applied to the signal paths NC and NO.

9.2.3 Application Curve
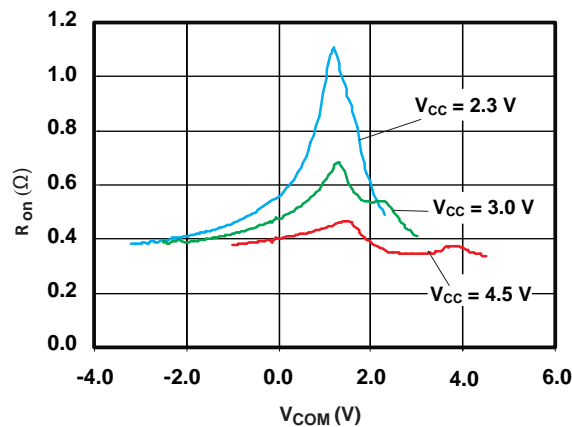
Figure 25. R_{on} vs V_{COM}

10 Power Supply Recommendations

The TS5A22364 operates from a single 2.3-V to 5.5-V supply. The device must be powered up with a supply voltage on VCC before a voltage can be applied to the signal paths NC and NO. TI recommends to include a 100-μs delay after VCC is at voltage before applying a signal on NC and NO paths

It is also good practice to place a 0.1-μF bypass capacitor on the supply pin VCC to GND to smooth out lower frequency noise to provide better load regulation across the frequency spectrum.

11 Layout

11.1 Layout Guidelines

TI recommends placing a bypass capacitor as close to the supply pin VCC as possible to help smooth out lower frequency noise to provide better load regulation across the frequency spectrum.

Minimize trace lengths and vias on the signal paths in order to preserve signal integrity.

11.2 Layout Example
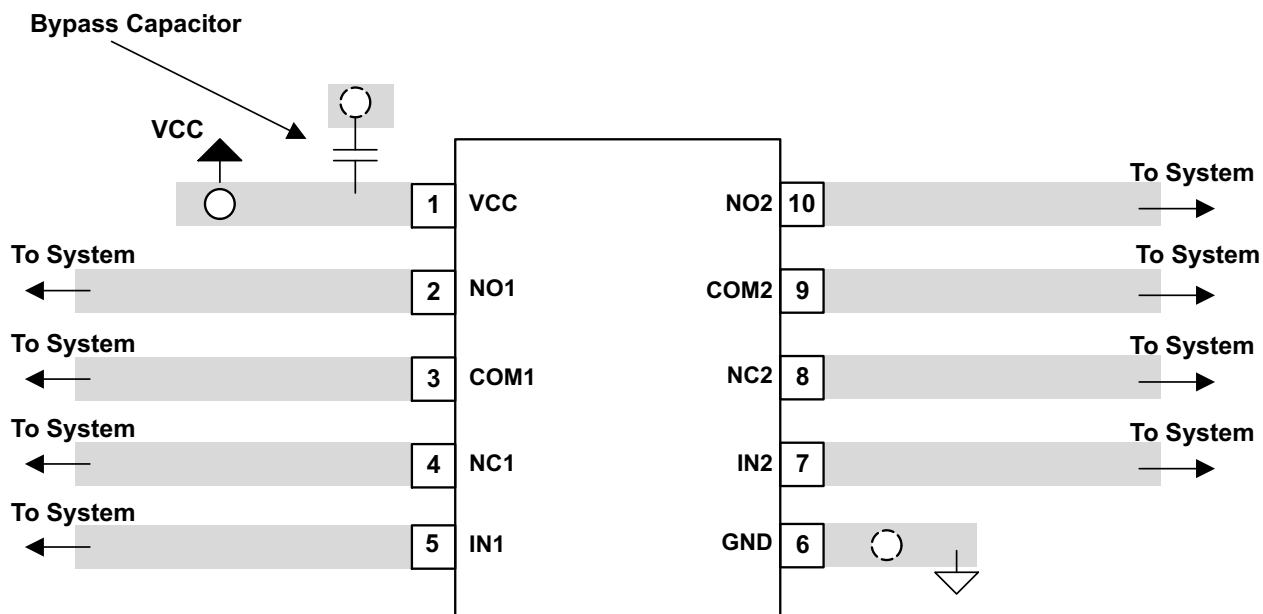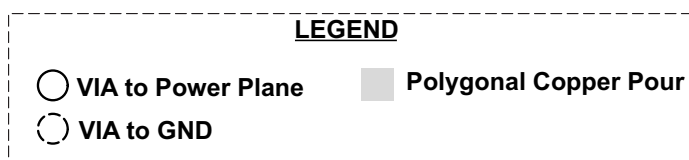
Figure 26. Layout Example of TS5A22364

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS5A22364DGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(38Q ~ 38R)	Samples
TS5A22364DGSRG4	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(38Q ~ 38R)	Samples
TS5A22364DRCR	ACTIVE	VSON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ZVF	Samples
TS5A22364YZPR	ACTIVE	DSBGA	YZP	10	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(38 ~ 382)	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TS5A22364 :

• Automotive: TS5A22364-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A22364DGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TS5A22364DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TS5A22364YZPR	DSBGA	YZP	10	3000	178.0	9.2	1.49	1.99	0.63	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A22364DGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TS5A22364DRCR	VSON	DRC	10	3000	367.0	367.0	35.0
TS5A22364YZPR	DSBGA	YZP	10	3000	220.0	220.0	35.0

DRC (S−PVSON−N10)   PLASTIC SMALL OUTLINE NO−LEAD

$\dfrac{3,10}{2,90}$ A

B

$\dfrac{3,10}{2,90}$

PIN 1 INDEX AREA
TOP AND BOTTOM

$\dfrac{1,00}{0,80}$

0,20 REF.

△ 0,08

SEATING PLANE

$\dfrac{0,05}{0,00}$

C

0,50

$10X \dfrac{0,50}{0,30}$

1   5

THERMAL PAD

SIZE AND SHAPE
SHOWN ON SEPARATE SHEET

10   6

$10X \dfrac{0,30}{0,18}$

⊕ | 0,10 Ⓜ | C | A | B |
| 0,05 Ⓜ | C |

4204102−3/L 09/11

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
      B. This drawing is subject to change without notice.
      C. Small Outline No−Lead (SON) package configuration.
      D. The package thermal pad must be soldered to the board for thermal and mechanical performance, if present.
      E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features
         and dimensions, if present

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DRC (S–PVSON–N10)   PLASTIC SMALL OUTLINE NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

PIN 1 INDICATOR
C 0,30

2x 0,30

Exposed Thermal Pad

0,23 4 Places

0,50

1,65 ±0,10

2,40±0,10
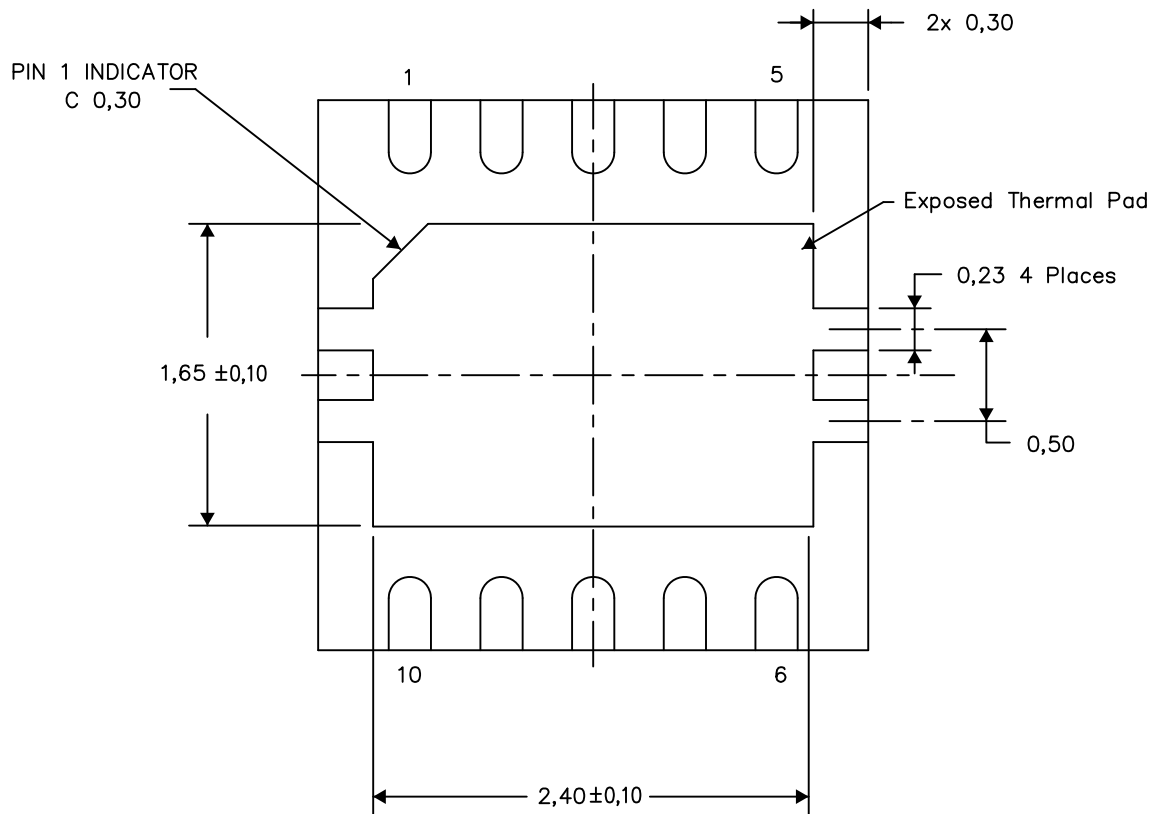
Bottom View
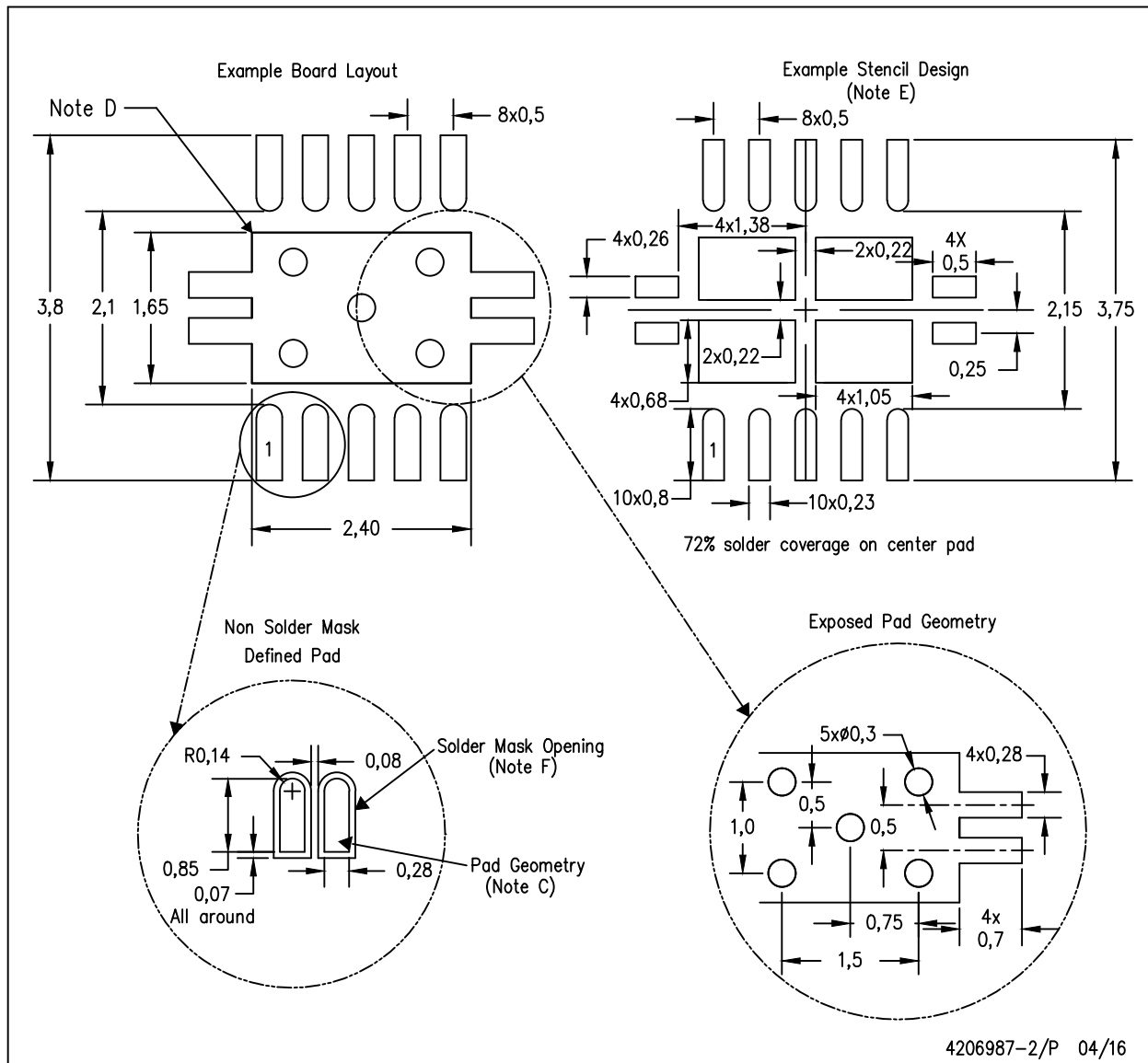
Exposed Thermal Pad Dimensions

4206565–3/Y 08/15

NOTE: A.   All linear dimensions are in millimeters

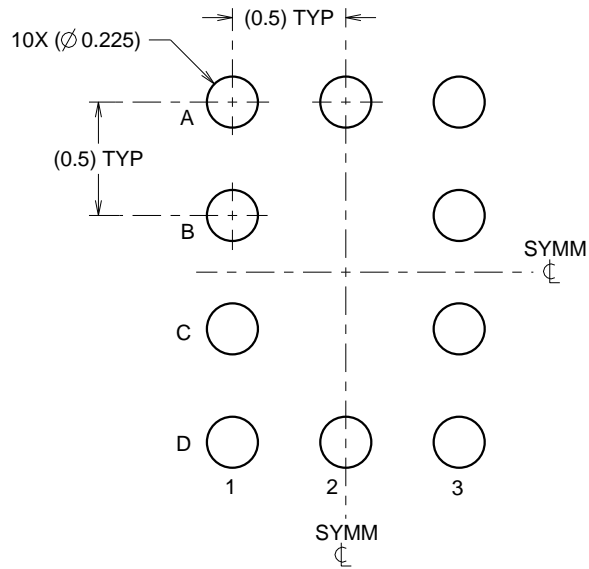DRC (S−PVSON−N10)   PLASTIC SMALL OUTLINE NO−LEAD

Example Board Layout

Note D

8x0,5

3,8 2,1 1,65

2,40

1

Example Stencil Design
(Note E)

8x0,5

4x0,26

4x1,38

2x0,22

4X
0,5

2x0,22

2,15 3,75

4x0,68

4x1,05

0,25

1

10x0,8

10x0,23

72% solder coverage on center pad

Non Solder Mask
Defined Pad

R0,14

0,08

Solder Mask Opening
(Note F)

0,85

0,07

0,28

Pad Geometry
(Note C)

All around

Exposed Pad Geometry

5xØ0,3

4x0,28

1,0

0,5

0,5

0,75

4x
0,7

1,5

4206987−2/P 04/16

NOTES: A. All linear dimensions are in millimeters.
        B. This drawing is subject to change without notice.
        C. Publication IPC−7351 is recommended for alternate designs.
        D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat−Pack
            Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets
            for specific thermal information, via requirements, and recommended board layout. These documents are available at
            www.ti.com <http://www.ti.com>.
        E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
            contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
        F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

TEXAS
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BALL A1
CORNER

B

E

A

D

0.5 MAX

0.19
0.15

BALL TYP

C

SEATING PLANE

△ 0.015 C

1 TYP

SYMM
₡

1.5
TYP

0.5
TYP

SYMM
₡

D

C

B

A

1   2   3

10X ⌀ 0.25
         0.21

⊕ 0.015Ⓢ C AⓈ BⓈ

0.5 TYP

D: Max = 1.89 mm, Min = 1.83 mm

E: Max = 1.39 mm, Min = 1.33 mm

4219350/A   06/2014

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
2. This drawing is subject to change without notice.

10X (⌀ 0.225)

(0.5) TYP

(0.5) TYP

A

B

SYMM
℄

C

D

1   2   3

SYMM
℄

LAND PATTERN EXAMPLE
SCALE:30X

(⌀ 0.225)
METAL

0.05 MAX

0.05 MIN

METAL
UNDER
MASK

SOLDER MASK
OPENING

(⌀ 0.225)
SOLDER MASK
OPENING

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED
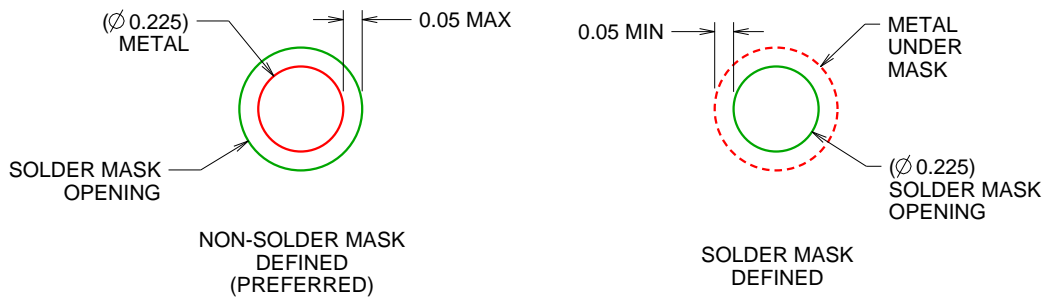
SOLDER MASK DETAILS
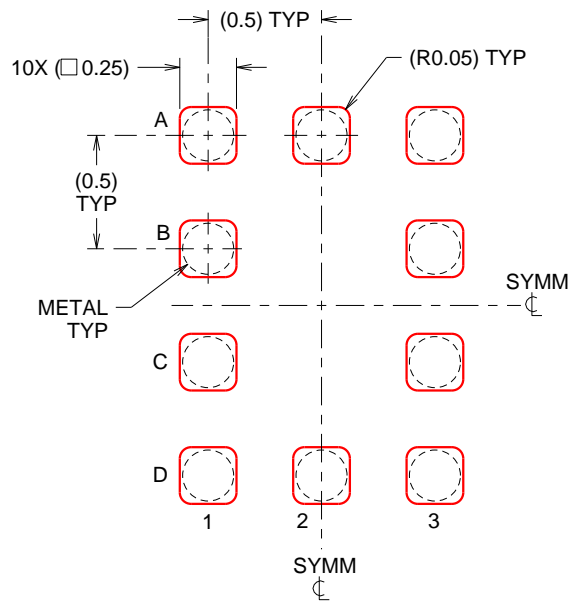NOT TO SCALE

4219350/A   06/2014

NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
   For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).

(0.5) TYP

10X (□ 0.25)

(R0.05) TYP

A

(0.5)
TYP

B

SYMM
₵

METAL
TYP

C

D

1   2   3

SYMM
₵

SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4219350/A   06/2014

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

DGS (S−PDSO−G10)   PLASTIC SMALL−OUTLINE PACKAGE

0,50

0,27
0,17   ⊕ | 0,08 Ⓜ

10   6

3,10
2,90   5,05
4,75

1   5

3,10
2,90

0,23
0,13

Gauge Plane

0°−8°   0,25

0,70
0,40

1,10 MAX   0,15
0,05

Seating Plane

◁ | 0,10

4073272/C 02/04

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash or protrusion.
         D.   Falls within JEDEC MO−187 variation BA.

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